



BC846BPN-AU

DUAL SURFACE MOUNT NPN/PNP TRANSISTORS (COMPLIMENTARY)

This device contains two electrically-isolated complimentary pair (NPN and PNP) general-purpose transistors. This device is ideal for portable applications where board space is at a premium.

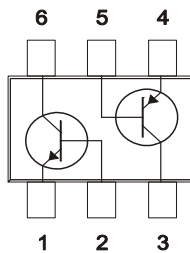
VOLTAGE 65 Volt **POWER** 225 mWatt

FEATURES

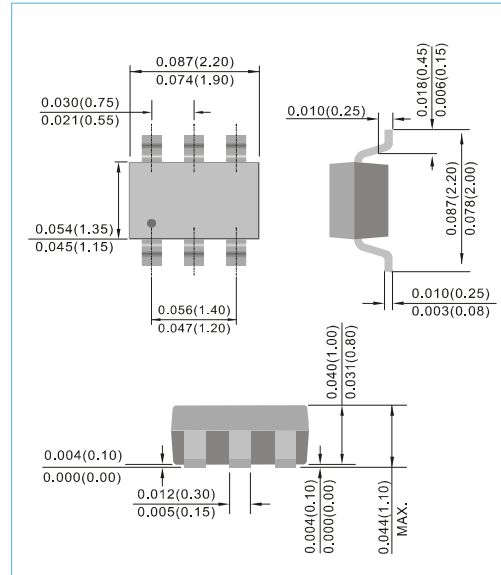
- General purpose amplifier applications
- Collector current $I_c = 100\text{mA}$
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard
- AEC-Q101 qualified

MECHANICAL DATA

- Case: SOT-363, Plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0002 ounces, 0.006 grams.
- Marking : 46P



SOT-363 Unit : inch(mm)



ABSOLUTE RATINGS

NPN

Parameter	Symbol	Value	Units
Collector - Emitter Voltage	V_{CEO}	65	V
Collector - Base Voltage	V_{CBO}	80	V
Emitter - Base Voltage	V_{EBO}	6.0	V
Collector Current - Continuous	I_c	100	mA

PNP

Parameter	Symbol	Value	Units
Collector - Emitter Voltage	V_{CEO}	-65	V
Collector - Base Voltage	V_{CBO}	-80	V
Emitter - Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_c	-100	mA



BC846BPN-AU

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Units
Max .Total Power Dissipation	P_{TOT}	225	mW
Junction Temperature range	T_J	-55 to 150	°C
Storage Temperature range	T_{STG}	-55 to 150	°C

ELECTRICAL CHARACTERISTICS

NPN

Parameter	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=10mA$	65	-	-	V
Collector - Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, V_{EB}=0$	80	-	-	V
Emitter - Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=1.0\mu A$	6.0	-	-	V
Collector-Base Cutoff Current	I_{CBO}	$V_{CB}=30V, I_E=0$	-	-	15	nA
DC Current Gain	h_{FE}	$I_C=2.0mA, V_{CE}=5V$	200	-	450	-
Collector - Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=10mA, I_B=0.5mA$ $I_C=100mA, I_B=5.0mA$	-	-	0.25 0.6	V
Base - Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=10mA, I_B=0.5mA$	0.6	-	0.9	V
Gain-Bandwidth Product	f_T	$V_{CE}=5V, I_C=10mA$ $f=100MHz$	100	-	-	MHz

PNP

Parameter	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=-10mA$	-65	-	-	V
Collector - Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=-10\mu A, V_{EB}=0$	-80	-	-	V
Emitter - Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=-1.0\mu A$	-5.0	-	-	V
Collector-Base Cutoff Current	I_{CBO}	$V_{CB}=-30V, I_E=0$	-	-	-15	nA
DC Current Gain	h_{FE}	$I_C=-2.0mA, V_{CE}=-5V$	220	-	475	-
Collector - Emitter Saturation Voltage	$V_{CE(SAT)}$	$I_C=-10mA, I_B=-0.5mA$ $I_C=-100mA, I_B=-5.0mA$	-	-	-0.3 -0.65	V
Base - Emitter Saturation Voltage	$V_{BE(SAT)}$	$I_C=-10mA, I_B=-0.5mA$	-0.6	-	-0.9	V
Gain-Bandwidth Product	f_T	$V_{CE}=-5V, I_C=-10mA$ $f=100MHz$	100	-	-	MHz



BC846BPN-AU

NPN ELECTRICAL CHARACTERISTICS CURVE

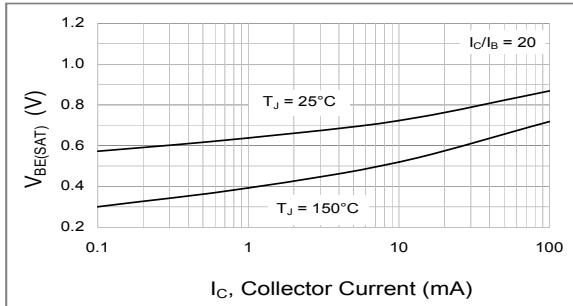


Fig.1 Base-Emitter Saturation Voltage

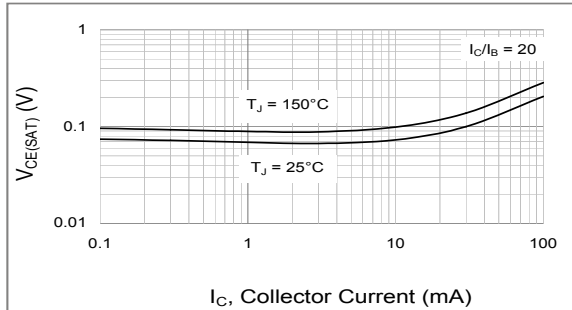


Fig.2 Collector-Emitter Saturation Voltage

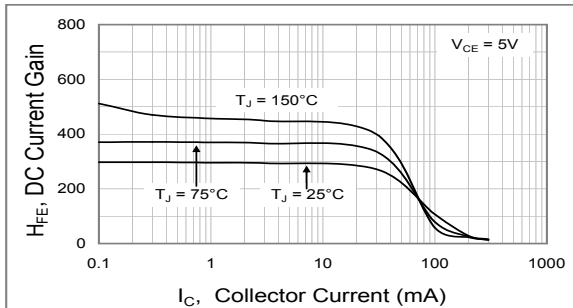


Fig.3 DC Current Gain

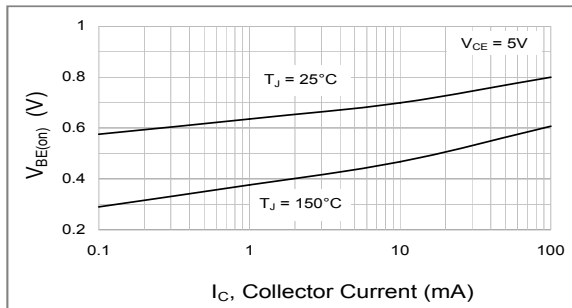


Fig.4 Base-Emitter Voltage

PNP ELECTRICAL CHARACTERISTICS CURVE

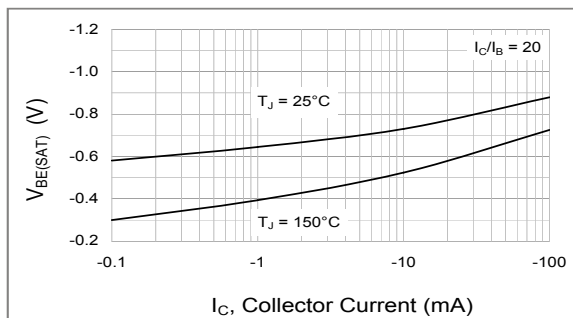


Fig.1 Base-Emitter Saturation Voltage

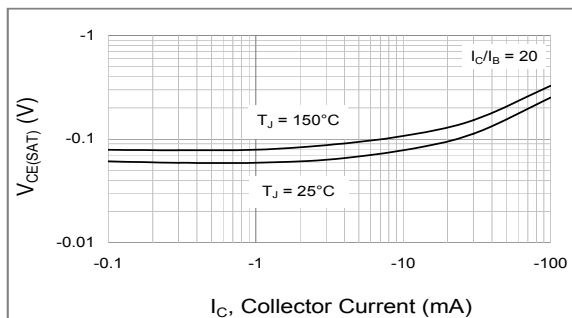


Fig.2 Collector-Emitter Saturation Voltage

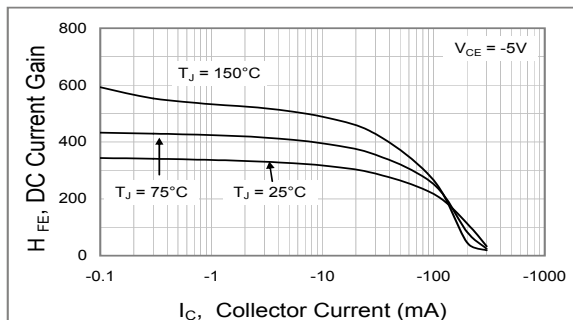


Fig.3 DC Current Gain

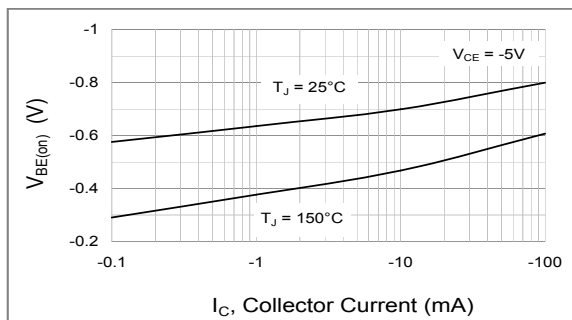
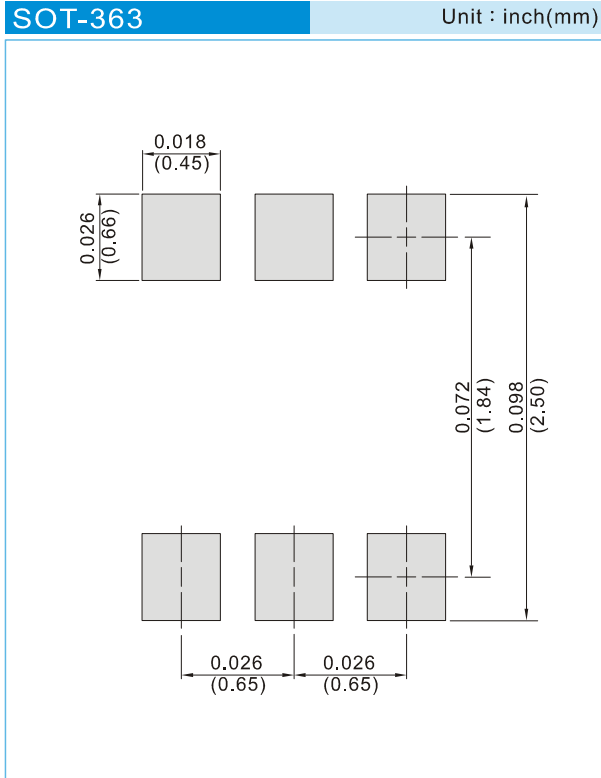


Fig.4 Base-Emitter Voltage



BC846BPN-AU

MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information
 - T/R - 10K per 13" plastic Reel
 - T/R - 3K per 7" plastic Reel



BC846BPN-AU

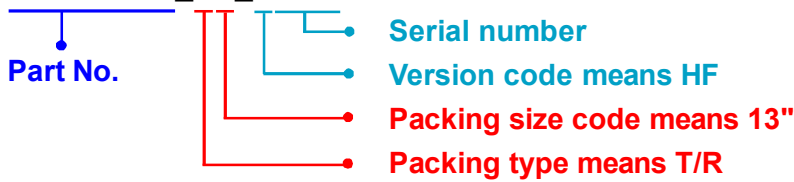
Part No_packing code_Version

BC846BPN-AU_R1_000A1

BC846BPN-AU_R2_000A1

For example :

RB500V-40_R2_00001



Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			